

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China













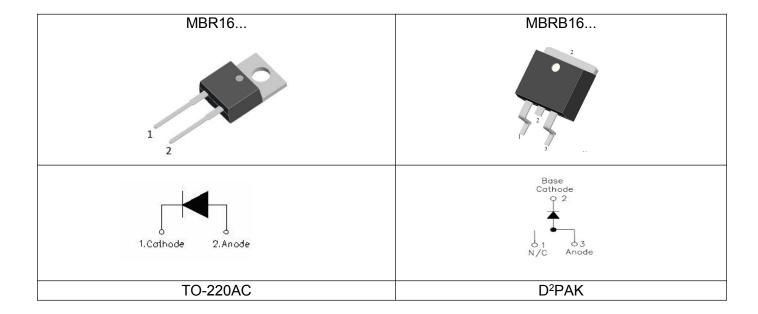
# MBR1635/MBR1645/MBRB1635/MBRB1645 SCHOTTKY RECTIFIER

#### **Features**

- 150°C T<sub>J</sub> operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- · High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request

#### **Applications**

- Switching power supply
- Redundant power subsystems
- Converters
- Free-Wheeling diodes
- Reverse battery protection



#### **Maximum Ratings:**

Characteristics	Symbol	Condition		Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	$oldsymbol{V_{RRM}}{oldsymbol{V_{RWM}}}$	-	35	(MBR1635)	V
DC Blocking Voltage	V <sub>RWM</sub> V <sub>R</sub>		45	(MBR1645)	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=80°C, rectangular wave form		16	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse, T <sub>C</sub> = 25 ℃		150	Α
Peak Repetitive Reverse Surge Current	I <sub>RRM</sub>	2.0 µ sec 1.0KHz		1.0	А

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •







### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@16A, Pulse, T <sub>J</sub> = 25 °C	0.54	0.63	V
	V <sub>F2</sub>	@16A, Pulse, T <sub>J</sub> = 125 °C	-	0.57	V
Reverse Current *	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25 \ ^{\circ}C$	0.04	1.0	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 125 \degree C$	20	40	mA
Junction Capacitance	Ст	@ $V_R = 5V$ , $T_C = 25$ °C $f_{SIG} = 1MHz$	700	1400	pF
Series Inductance	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/µs

 $<sup>^*</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2%

### **Thermal-Mechanical Specifications:**

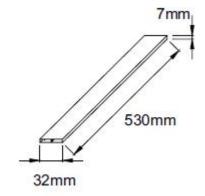
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>θJC</sub>	DC operation	1.5	°C/W
Typical Thermal Resistance Case to Heat Sink	R <sub>0CS</sub>	Mounting surface, smooth and greased(only for TO-220)	0.50	°C/W
Case Style	TO-220ACD <sup>2</sup> PAK			

# **Tube Specification**

Device	Package	Weight	Shipping
MBR16	TO-220AC	1.8g	50pcs / tube
MBRB16	D² PAK	1.85g	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# **Tube Specification(TO-220AC)**

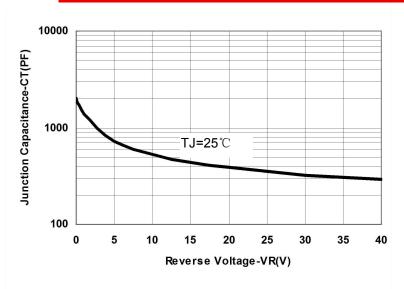








# **Ratings and Characteristics Curves**



100 10 Reverse Current (MA) TJ=125℃ 1 0.1 0.01 TJ=25℃ 0.001 20 10 25 30 35 45 15 40 Reverse Voltage (%)

Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

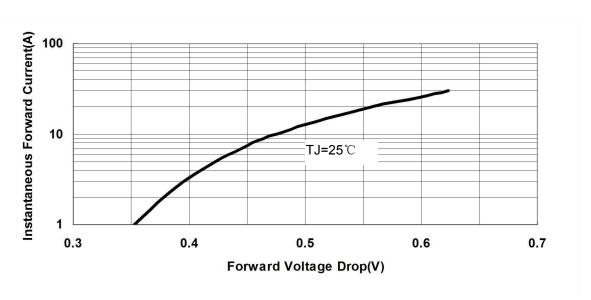


Fig.3-Typical Instantaneous Forward Voltage Characteristics

<sup>•</sup> http://www.smc-diodes.com - sales@ smc-diodes.com •



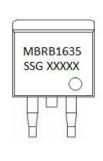






# **Marking Diagram**





Where XXXXX is YYWWL

MBR = Device Type
B = Package type
16 = Forward Current (16A)
35/45 = Reverse Voltage (35/45V)

 SSG
 = SSG

 YY
 = Year

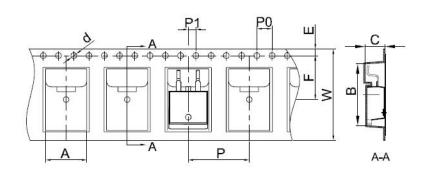
 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

# Carrier Tape Specification D<sup>2</sup>PAK



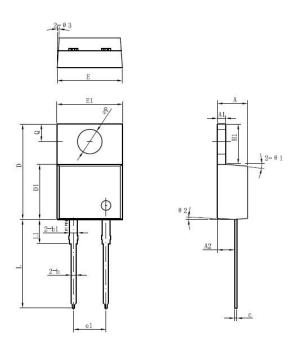
Symbol	Millimeters			
Syllibol	Min.	Max.		
Α	10.70	10.90		
В	16.03	16.23		
С	5.11	5.31		
d	1.45	1.65		
E	1.65	1.85		
F	11.40	11.60		
P0	3.90	4.10		
Р	15.90	16.10		
P1	1.90	2.10		
W	23.90	24.30		





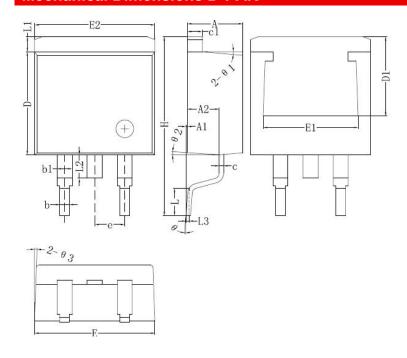


# **Mechanical Dimensions TO-220AC**



Symbol	Dimensions in millimeters			
	Min. Typical		Max.	
Α	4.47	4.70	4.85	
A1	1.17	1.27	1.37	
A2	2.52	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
D	14.64	14.94	15.24	
D1	8.50	8.07	8.90	
E	10.01	10.16	10.31	
E1	9.98	10.18	10.38	
e1	4.98	5.08	5.18	
H1	6.04	6.24	6.44	
L	13.00	13.86	14.08	
L1	3.56	3.80	3.96	
ФР	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		5°		
Θ2		4°		
Θ3		4°		

# Mechanical Dimensions D<sup>2</sup>PAK



Symbol	Millimeters			
_	Min.	Typical	Max.	
Α	4.47	4.70	4.85	
<b>A</b> 1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.50	8.70	8.90	
D1	6.40			
Е	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.31	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.74	
L1	1.12	1.27	1.42	
L2	1.30		2.20	
L3		0.25BSC		
е	0	-	8°	
e1		5°		
e2		4°		
е3		4°		

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •



# MBR1635/MBRB1635 MBR1645/MBRB1645

#### Technical Data Data Sheet N0032, Rev. A





#### DISCLAIMER:

- 1- The information given herein, including the specifications and dimensions, is subject to change without prior notice to improve product characteristics. Before ordering, purchasers are advised to contact the SMC Sangdest Microelectronics (Nanjing) Co., Ltd sales department for the latest version of the datasheet(s).
- 2- In cases where extremely high reliability is required (such as use in nuclear power control, aerospace and aviation, traffic equipment, medical equipment, and safety equipment), safety should be ensured by using semiconductor devices that feature assured safety or by means of users' fail-safe precautions or other arrangement.
- 3- In no event shall SMC Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any damages that may result from an accident or any other cause during operation of the user's units according to the datasheet(s). SMC Sangdest Microelectronics (Nanjing) Co., Ltd assumes no responsibility for any intellectual property claims or any other problems that may result from applications of information, products or circuits described in the datasheets.
- 4- In no event shall SMC Sangdest Microelectronics (Nanjing) Co., Ltd be liable for any failure in a semiconductor device or any secondary damage resulting from use at a value exceeding the absolute maximum rating.
- 5- No license is granted by the datasheet(s) under any patents or other rights of any third party or SMC Sangdest Microelectronics (Nanjing)
- 6- The datasheet(s) may not be reproduced or duplicated, in any form, in whole or part, without the expressed written permission of SMC Sangdest Microelectronics (Nanjing) Co., Ltd.
- 7- The products (technologies) described in the datasheet(s) are not to be provided to any party whose purpose in their application will hinder maintenance of international peace and safety nor are they to be applied to that purpose by their direct purchasers or any third party. When exporting these products (technologies), the necessary procedures are to be taken in accordance with related laws and regulations..